



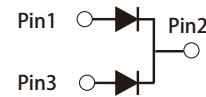
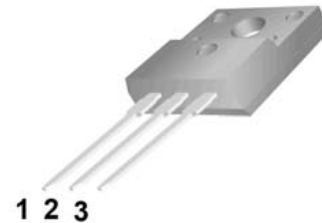
SBT20L150F

Features:

- Low power loss, high efficiency.
- High surge capacity.
- High frequency operation.
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- Metal silicon junction, majority carrier conduction.
- High current Capability, low forward voltage drop.
- Guard ring for over voltage protection.

RoHS
COMPLIANT

TO-220AB



1.Anode 2.Cathode 3. Anode

Absolute Maximum Ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	150	V
Maximum average forward rectified current	Per leg	10	A
	Total device	20	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated TL)	I_{FSM}	200	A
Operating junction and Storage temperature range	T_J, T_{stg}	-55 to +150	°C

Electrical Characteristics (Ta=25°C Unless otherwise noted)

Parameter	Test Conditions	Symbol	TYP.	MAX.	Unit
Instaneous forward voltage (Per leg)	IF=5.0A	VF ¹⁾	0.70	-	V
	IF=10.0A		0.80	0.83	
Reverse Current	VR=150V	IR ²⁾	T _A =25°C	20	μA
			T _A =125°C	1	-

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Pulse test: pulse width ≤ 40ms

Thermal Characteristics

Parameter	Symbol	Value	Unit
Typical thermal resistance ³⁾	$R_{\theta JC}$	4.5	°C/W

3.Thermal resistance from junction to case



RATING AND CHARACTERISTIC CURVES

FIG. 1- FORWARD CURRENT DERATING CURVE

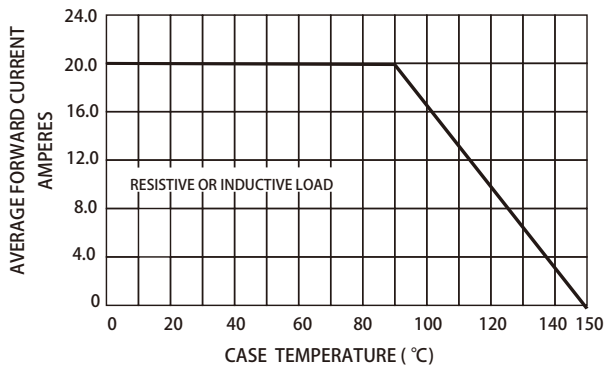


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

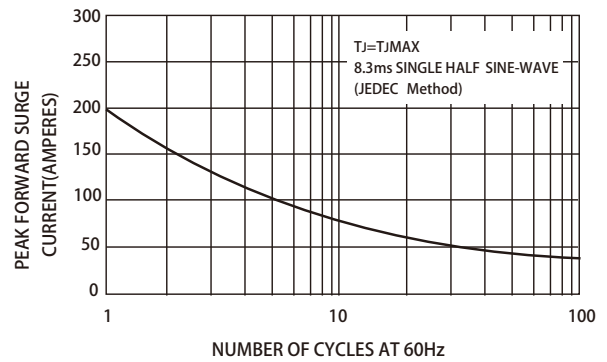


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

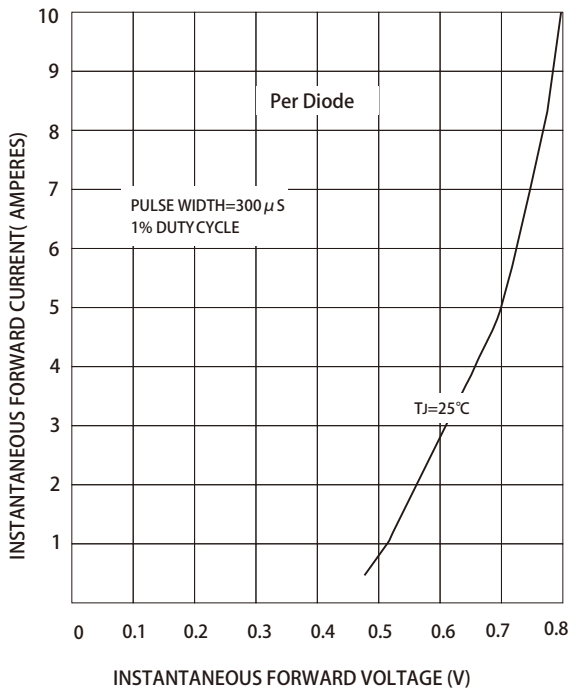
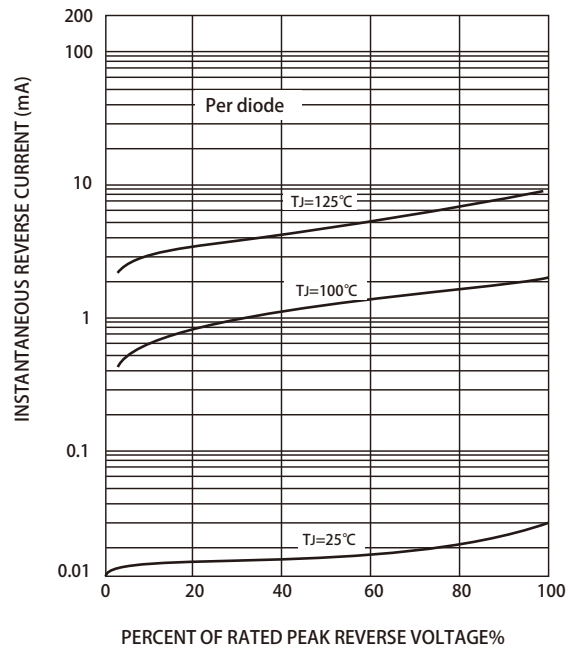


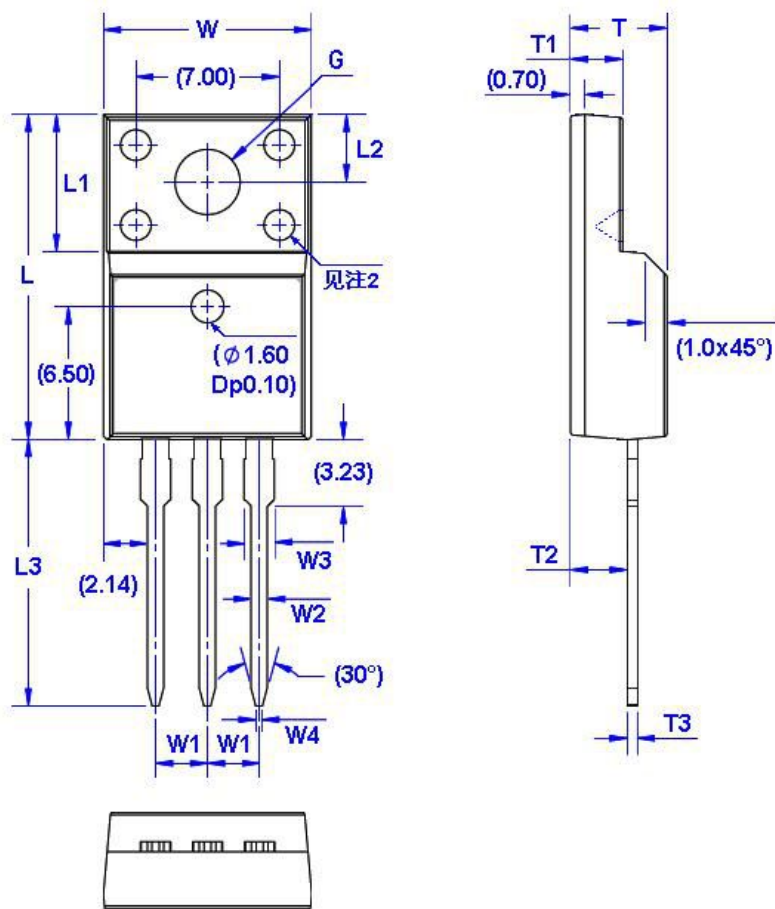
FIG. 4-TYPICAL REVERSE CHARACTERISTICS





Package Dimension

TO-220AB



Symbol	Size		Symbol	Size		Symbol	Size		Symbol	Size	
	Min	Max		Min	Max		Min	Max		Min	Max
W	9.96	10.36	W4	0.25	0.45	L3	12.78	13.18	T3	0.45	0.60
W1	2.54 (TYP)		L	15.67	16.07	T	4.50	4.90	G(Φ)	3.08	3.28
W2	0.70	0.90	L1	6.48	6.88	T1	2.34	2.74			
W3	1.24	1.47	L2	3.20	3.40	T2	2.56	2.96			